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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
10/646,709	08/25/2003	Sadayuki Ohnishi	Q76993	9821
23373 7:	590 12/01/2004		EXAMINER	
SUGHRUE MION, PLLC			CAO, PHAT X	
2100 PENNSYLVANIA AVENUE, N.W. SUITE 800		ART UNIT	PAPER NUMBER	
WASHINGTO:	N, DC 20037		2814	
			DATE MAILED: 12/01/2004	1

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)			
	10/646,709	OHNISHI, SADAYUKI			
Office Action Summary	Examiner	Art Unit			
	Phat X. Cao	2814			
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply					
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a reply If NO period for reply is specified above, the maximum statutory period we Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	6(a). In no event, however, may a reply be tim within the statutory minimum of thirty (30) days ill apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONED	ely filed  will be considered timely. the mailing date of this communication.  (35 U.S.C. § 133).			
Stațus	•				
Responsive to communication(s) filed on 16 Section 2a) ☐ This action is <b>FINAL</b> . 2b) ☐ This 3) ☐ Since this application is in condition for allowant closed in accordance with the practice under Expression 2.	action is non-final. ce except for formal matters, pro				
Disposition of Claims					
<ul> <li>4) ☐ Claim(s) 1-24 is/are pending in the application.</li> <li>4a) Of the above claim(s) 14-24 is/are withdraw</li> <li>5) ☐ Claim(s) is/are allowed.</li> <li>6) ☐ Claim(s) 1-13 is/are rejected.</li> <li>7) ☐ Claim(s) is/are objected to.</li> <li>8) ☐ Claim(s) are subject to restriction and/or</li> </ul>					
Application Papers					
9) The specification is objected to by the Examiner 10) The drawing(s) filed on is/are: a) access Applicant may not request that any objection to the of Replacement drawing sheet(s) including the correction of the oath or declaration is objected to by the Examiner  11) The oath or declaration is objected to by the Examiner  12. **The Specification**  13. **The Specification**  14. **The Specification**  15. **The Specification**  16. **The Specification**  17. **The Specification**  18. **The Specification**  19. **The Specification**  10. **The Specification**  11. **The Specification**  11. **The Specification**  12. **The Specification**  13. **The Specification**  14. **The Specification**  15. **The Specification**  16. **The Specification**  17. **The Specification**  18. **The Specification**  19. **The Specification**  19. **The Specification**  19. **The Specification**  11. **The Specification**  11. **The Specification**  11. **The Specification**  12. **The Specification**  13. **The Specification**  14. **The Specification**  15. **The Specification**  16. **The Specification**  17. **The Specification**  17. **The Specification**  18. **The Specification**  19. **The Spe	epted or b) objected to by the Edirawing(s) be held in abeyance. See on is required if the drawing(s) is objected to by	e 37 CFR 1.85(a). ected to. See 37 CFR 1.121(d).			
	ammer. Note the attached Office	ACTION OF TOTAL 132.			
Priority under 35 U.S.C. § 119  12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).  a) All b) Some * c) None of:  1. Certified copies of the priority documents have been received.  2. Certified copies of the priority documents have been received in Application No  3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).  * See the attached detailed Office action for a list of the certified copies not received.					
Attachment(s)  1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date 8/25/03.	4) Interview Summary Paper No(s)/Mail Da 5) Notice of Informal Pa	•			

#### **DETAILED ACTION**

1. Applicant's election without traverse of Group I, claims 1-13 in the reply filed on 9/3/04 is acknowledged.

#### **Specification**

2. The title of the invention is not descriptive. A new title is required that is clearly indicative of the invention to which the claims are directed.

### Claim Objections

3. Claim 12 objected to because of the following informalities: in claim 12, line 2, "said metal diffusion barrier" should be changed to "a metal diffusion barrier".

Appropriate correction is required.

## Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 5. Claims 1-7 and 9-11 are rejected under 35 U.S.C. 103(a) as being unpatentable over Lee (US. 2003/0067077) in view of Lauterbach et al (US. 6,313,517).

Regarding claims 1-3 and 9, Lee (Fig. 1I) discloses a semiconductor device comprising a semiconductor substrate 100 and an interlayer dielectric film formed on the semiconductor substrate, the interlayer dielectric film including a lamination consisting essentially of an adhesive film 118 made of benzocyclobutene polymer

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(BCB) having benzene ring (aromatic ring) in its molecule (par. [0019]) and a low dielectric constant film 120 constituted essentially by an organic low dielectric constant material having a specific dielectric constant not greater than 4 (pars. [0014] and [0021]).

Lee does not disclose that the adhesive film 118 is a silicon-based compound.

However, one skilled in the art would recognize that the adhesive film 118 of Lee would be formed by a silicon-based compound because it is made of a benzocyclobutene unit (BCB) in its molecule, as taught by Lauterbach (column 3, lines 50-67 through column 4, lines 1-16).

Regarding claims 4-7, Lauterbach (column 3, lines 50-66 through column 4, lines 1-16) further teaches that BCB is polymer silicon-based compound containing a silylene unit and formed through polymerization of a monomer containing a divinylsiloxane bisbenzocyclobutene unit. It is noted that the process limitations (formed through polymerization of a monomer containing a divinylsiloxane bisbenzocyclobutene unit, formed through plasma polymerization of the monomer) recited in a "product by process" claim would not carry patentable weight in a claim drawn to structure because distinct structure is not necessarily produced. <u>In re Thorpe</u>, 227 USPQ 964 (Fed. Cir. 1985).

Regarding claims 10-11, Lee (Fig. 1I) further discloses a metal wiring 116a formed on the semiconductor substrate 100, wherein the adhesive film 118 is formed in contact with the metal wiring 116a and the low dielectric constant film 120 is formed o the adhesive film 118.

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6. Claims 12-13 are rejected under 35 U.S.C. 103(a) as being unpatentable over Lee and Lauterbach et al as applied to claim 10 above, and further in view of Aoki et al (US. 6,787,480).

Neither Lee nor Lauterbach discloses a cap metal formed on the metal wiring and under the adhesive film.

However, Aoki (Fig. 4c) teaches the forming of a cap metal 24/25 (not labeled, see Fig. 3) on a metal wiring 17 and under a lamination of an adhesive film 7 and an interlayer dielectric 19. Accordingly, it would have been obvious to form the cap metal on the meal wiring 116a and between the metal wiring 116a and the adhesive film 118 of Lee because as taught by Aoki, such cap metal structure would function as a metal diffusion barrier to suppress the increases in interconnection resistance and contact resistance (column 9, lines 64-67 through column 10, lines 1-12).

7. Claims 1-12 are rejected under 35 U.S.C. 103(a) as being unpatentable over Barth et al (US. 2004,0173908) in view of Lee (US. 2003/0067077).

Regarding claims 1-3 and 9, Barth (Fig. 2) discloses a semiconductor device comprising a semiconductor substrate 110 and an interlayer dielectric film formed on the semiconductor substrate 110, the interlayer dielectric film including a lamination consisting essentially of an adhesive film 118 (par. [0033]) and a low dielectric constant film 119 constituted essentially by an organic low dielectric constant material having a specific dielectric constant not greater than 4 (par. [0031]) and contacting the adhesive film 118.

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Barth does not disclose that the adhesive film 118 is a silicon-based compound of BCB having an aromatic ring.

However, Lee (Fig. 1I) teaches an interlayer dielectric film including a lamination consisting essentially of an adhesive film 118 constituted essentially by a silicon-based compound of BCB having a benzene ring (aromatic ring) (par. [0019]) and an organic low dielectric constant film 120 having a specific dielectric constant not greater than 4 (pars. [0014] and [0021]) and contacting the adhesive film 118. Accordingly, it would have been obvious to form the adhesive film 118 of Barth with the material as set forth above because as taught by Lee, such BCB adhesive layer would provide a good adhesion to the metal wiring layer/organic dielectric layer and would prevent a crack issue (par. [0019]).

Regarding claims 4 and 7, the adhesive layer 118 of Lee would contain a silylene unit and would not contain an Si-H bond because it is a polymer of BCB (par. [0019]), which is the same material as BCB as claimed.

Regarding claims 5-6, the process limitations (formed through polymerization of a monomer containing a divinylsiloxane bisbenzocyclobutene unit, formed through plasma polymerization of the monomer) recited in a "product by process" claim would not carry patentable weight in a claim drawn to structure because distinct structure is not necessarily produced. <u>In re Thorpe</u>, 227 USPQ 964 (Fed. Cir. 1985).

Regarding claims 8, 10 and 12, Barth (Fig. 2) further discloses a metal wiring 115 formed on the semiconductor substrate 110, a metal diffusion barrier 116 of copper alloy is formed on the metal wiring 115, and the adhesive film 118 and the organic low

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dielectric constant film 119 of MSQ (par. [0031]) are formed in this sequence on the

metal diffusion barrier 116.

Regarding claim 11, Lee (Fig. 1I) further teaches that the adhesive film 118 is

formed in contact with the metal wiring 116a and the low dielectric constant film 120 is

formed on the adhesive film 118.

Any inquiry concerning this communication or earlier communications from the 8.

examiner should be directed to Phat X. Cao whose telephone number is (571) 272-

1703. The examiner can normally be reached on Monday - Thursday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Wael Fahmy can be reached on (571) 272-1705. The fax phone number for

the organization where this application or proceeding is assigned is 703-872-9306.

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PRIMARY EXAMINER

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November 23, 2004